TOSHIBA Transistor Silicon NPN Triple Diffused Type

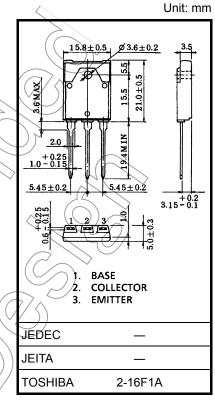
2SC4690

Power Amplifier Applications

- High breakdown voltage: VCEO = 140 V (min)
- Complementary to 2SA1805
- Suitable for use in 70-W high fidelity audio amplifier's output stage

Absolute Maximum Ratings (Tc = 25°C)

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V _{CBO}	140	(γ)	
Collector-emitter voltage		V _{CEO}	140	$\langle u \rangle$	
Emitter-base voltage		V _{EBO}	5	\ \ \ \	
Collector current	DC	IC	10	> A	
	Pulse	I _{CP}	20		
Base current		I _B		Α	
Collector power dissipation		Da <	80	W	
(Tc = 25°C)		Pc	00	< ~	
Junction temperature		Tj	150	°C	
Storage temperature range		Tstg	_55 to 150	°C	

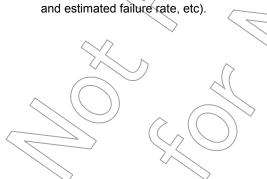


Weight: 5.8 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high

temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc.)

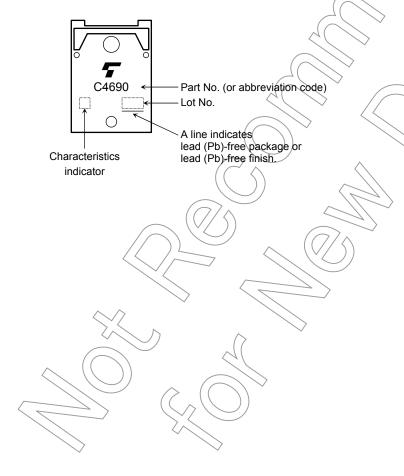


Electrical Characteristics (Tc = 25°C)

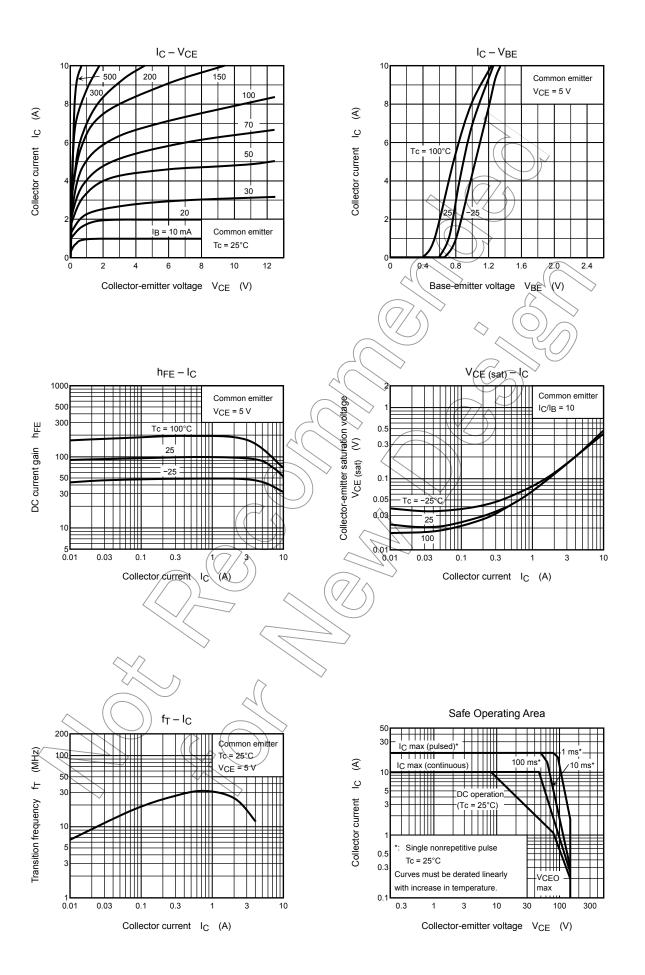
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I _{CBO}	V _{CB} = 140 V, I _E = 0	_	_	5.0	μΑ
Emitter cut-off current	I _{EBO}	V _{EB} = 5 V, I _C = 0	_	_	5.0	μΑ
Collector-emitter breakdown voltage	V (BR) CEO	I _C = 50 mA, I _B = 0	140	_	_	٧
DC current gain	h _{FE (1)} (Note)	V _{CE} = 5 V, I _C = 1 A	55	7	160	
	h _{FE (2)}	V _{CE} = 5 V, I _C = 5 A	35	85	_	
Collector-emitter saturation voltage	V _{CE} (sat)	I _C = 7 A, I _B = 0.7 A	\bigcirc	0.3	2.0	V
Base-emitter voltage	V _{BE}	V _{CE} = 5 V, I _C = 5 A	_	0.9	1.5	V
Transition frequency	f _T	V _{CE} = 5 V, I _C = 1 A	_	30	_	MHz
Collector output capacitance	C _{ob}	V _{CB} = 10 V, I _E = 0, f = 1 MHz	_	220	_	pF

Note: $h_{FE(1)}$ classification R: 55 to 110, O: 80 to 160





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